

T495, Tantalum, MnO2 Tantalum, 100 uF, 10%, 6.3 VDC, SMD, MnO2, Molded, Low ESR, 75 mOhms, 6032, Height Max = 2.8mm



General Information	
Series:	T495
Dielectric:	MnO2 Tantalum
Style:	SMD Chip
Description:	SMD, MnO2, Molded, Low ESR
Features:	Low ESR
RoHS:	Yes
Termination:	Tin
AEC-Q200:	No
Shelf Life:	156 Weeks
MSL:	1

Dimensions	
Footprint	6032
L	6mm +/-0.3mm
W	3.2mm +/-0.3mm
H	2.5mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.2mm +/-0.1mm
A	2.9mm MIN
B	0.5mm +/-0.15mm
E	2.4mm REF
G	2.8mm REF
P	0.9mm REF
R	1mm REF
X	0.1mm +/-0.1mm

Specifications	
Capacitance:	100 uF
Capacitance Tolerance:	10%
Voltage DC:	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range:	-55/+125°C
Rated Temperature:	85°C
Dissipation Factor:	8% 120Hz 20C
Failure Rate:	N/A
Resistance:	75 mOhms (100kHz)
Ripple Current:	1211 mA (rms, 100kHz 25C), 1089.9 mA (rms, 85C), 484.4 mA (rms, 125C)
Leakage Current:	6.3 uA (5min 20°C)

Packaging Specifications	
Weight:	224.48 mg
Packaging:	T&R, 178mm
Packaging Quantity:	500

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